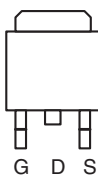


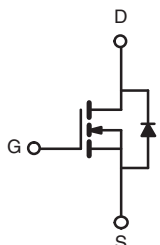
# Automotive N-Channel 30 V (D-S) 175 °C MOSFET

## PRODUCT SUMMARY

|                                               |        |
|-----------------------------------------------|--------|
| $V_{DS}$ (V)                                  | 30     |
| $R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 10$ V  | 0.0015 |
| $R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 4.5$ V | 0.0020 |
| $I_D$ (A)                                     | 120    |
| Configuration                                 | Single |

**TO-263**


Top View



N-Channel MOSFET

## FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- 100 %  $R_g$  and UIS Tested
- AEC-Q101 Qualified<sup>d</sup>
- Compliant to RoHS Directive 2002/95/EC

AUTOMOTIVE  
GRADE

**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## ORDERING INFORMATION

|                                 |                    |
|---------------------------------|--------------------|
| Package                         | TO-263             |
| Lead (Pb)-free and Halogen-free | SQM120N03-1m5L-GE3 |

## ABSOLUTE MAXIMUM RATINGS ( $T_C = 25$ °C, unless otherwise noted)

| PARAMETER                                                 | SYMBOL         | LIMIT          | UNIT |
|-----------------------------------------------------------|----------------|----------------|------|
| Drain-Source Voltage                                      | $V_{DS}$       | 30             | V    |
| Gate-Source Voltage                                       | $V_{GS}$       | $\pm 20$       |      |
| Continuous Drain Current <sup>a</sup>                     | $I_D$          | $T_C = 25$ °C  | A    |
|                                                           |                | $T_C = 125$ °C |      |
| Continuous Source Current (Diode Conduction) <sup>a</sup> | $I_S$          | 120            |      |
| Pulsed Drain Current <sup>b</sup>                         | $I_{DM}$       | 480            |      |
| Single Pulse Avalanche Current                            | $I_{AS}$       | 82             |      |
| Single Pulse Avalanche Energy                             |                | 336            | mJ   |
| Maximum Power Dissipation <sup>b</sup>                    | $P_D$          | $T_C = 25$ °C  | W    |
|                                                           |                | $T_C = 125$ °C |      |
| Operating Junction and Storage Temperature Range          | $T_J, T_{stg}$ | - 55 to + 175  | °C   |

## THERMAL RESISTANCE RATINGS

| PARAMETER                | SYMBOL     | LIMIT | UNIT |
|--------------------------|------------|-------|------|
| Junction-to-Ambient      | $R_{thJA}$ | 40    | °C/W |
| Junction-to-Case (Drain) | $R_{thJC}$ | 0.4   |      |

### Notes

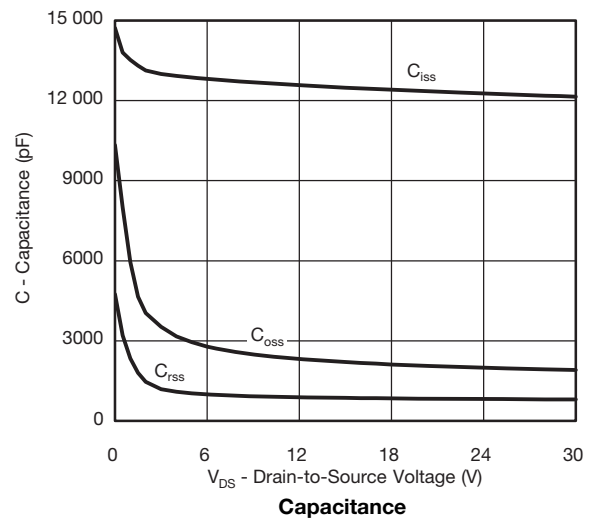
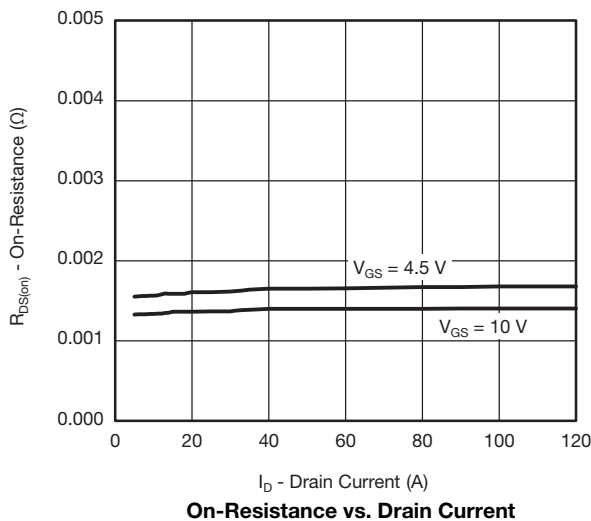
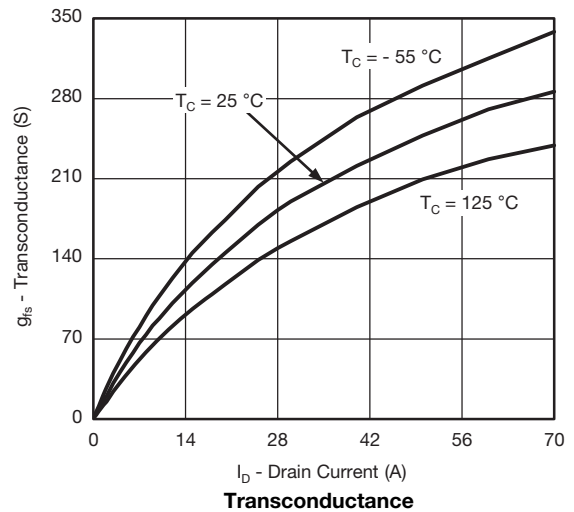
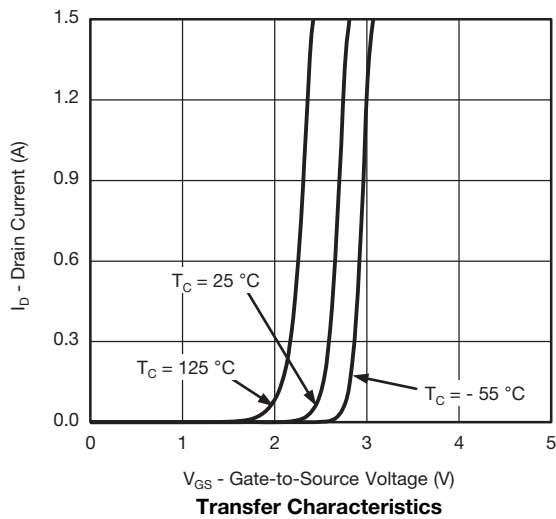
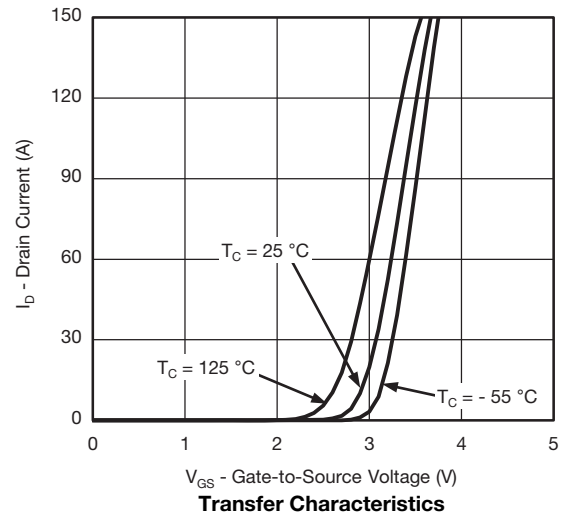
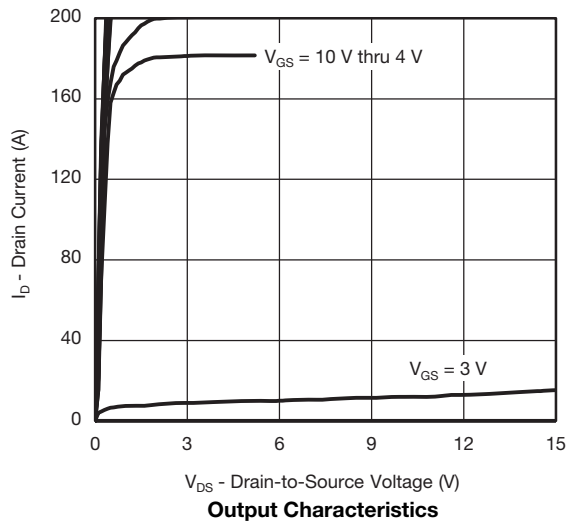
- Package limited.
- Pulse test; pulse width  $\leq 300$   $\mu$ s, duty cycle  $\leq 2$  %.
- When mounted on 1" square PCB (FR-4 material).
- Parametric verification ongoing.

| SPECIFICATIONS (T <sub>C</sub> = 25 °C, unless otherwise noted) |                     |                                                                                                                        |                                                 |      |        |        |      |
|-----------------------------------------------------------------|---------------------|------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------|------|--------|--------|------|
| PARAMETER                                                       | SYMBOL              | TEST CONDITIONS                                                                                                        |                                                 | MIN. | TYP.   | MAX.   | UNIT |
| Static                                                          |                     |                                                                                                                        |                                                 |      |        |        |      |
| Drain-Source Breakdown Voltage                                  | V <sub>DS</sub>     | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA                                                                         |                                                 | 30   | -      | -      | V    |
| Gate-Source Threshold Voltage                                   | V <sub>GS(th)</sub> | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA                                                            |                                                 | 1.5  | 2.0    | 2.5    |      |
| Gate-Source Leakage                                             | I <sub>GSS</sub>    | V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V                                                                        |                                                 | -    | -      | ± 100  | nA   |
| Zero Gate Voltage Drain Current                                 | I <sub>DSS</sub>    | V <sub>GS</sub> = 0 V                                                                                                  | V <sub>DS</sub> = 30 V                          | -    | -      | 1      | μA   |
|                                                                 |                     | V <sub>GS</sub> = 0 V                                                                                                  | V <sub>DS</sub> = 30 V, T <sub>J</sub> = 125 °C | -    | -      | 50     |      |
|                                                                 |                     | V <sub>GS</sub> = 0 V                                                                                                  | V <sub>DS</sub> = 30 V, T <sub>J</sub> = 175 °C | -    | -      | 250    |      |
| On-State Drain Current <sup>a</sup>                             | I <sub>D(on)</sub>  | V <sub>GS</sub> = 10 V                                                                                                 | V <sub>DS</sub> ≥ 5 V                           | 120  | -      | -      | A    |
| Drain-Source On-State Resistance <sup>a</sup>                   | R <sub>DS(on)</sub> | V <sub>GS</sub> = 10 V                                                                                                 | I <sub>D</sub> = 30 A                           | -    | 0.0014 | 0.0015 | Ω    |
|                                                                 |                     | V <sub>GS</sub> = 10 V                                                                                                 | I <sub>D</sub> = 30 A, T <sub>J</sub> = 125 °C  | -    | -      | 0.0023 |      |
|                                                                 |                     | V <sub>GS</sub> = 10 V                                                                                                 | I <sub>D</sub> = 30 A, T <sub>J</sub> = 175 °C  | -    | -      | 0.0028 |      |
|                                                                 |                     | V <sub>GS</sub> = 4.5 V                                                                                                | I <sub>D</sub> = 20 A                           | -    | 0.0016 | 0.0020 |      |
| Forward Transconductance <sup>b</sup>                           | g <sub>fs</sub>     | V <sub>DS</sub> = 15 V, I <sub>D</sub> = 30 A                                                                          |                                                 | -    | 190    | -      | S    |
| Dynamic <sup>b</sup>                                            |                     |                                                                                                                        |                                                 |      |        |        |      |
| Input Capacitance                                               | C <sub>iss</sub>    | V <sub>GS</sub> = 0 V                                                                                                  | V <sub>DS</sub> = 15 V, f = 1 MHz               | -    | 12 484 | 15 605 | pF   |
| Output Capacitance                                              | C <sub>oss</sub>    |                                                                                                                        |                                                 | -    | 2204   | 2755   |      |
| Reverse Transfer Capacitance                                    | C <sub>rss</sub>    |                                                                                                                        |                                                 | -    | 860    | 1075   |      |
| Total Gate Charge <sup>c</sup>                                  | Q <sub>g</sub>      | V <sub>GS</sub> = 10 V                                                                                                 | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 120 A  | -    | 179    | 270    | nC   |
| Gate-Source Charge <sup>c</sup>                                 | Q <sub>gs</sub>     |                                                                                                                        |                                                 | -    | 34     | -      |      |
| Gate-Drain Charge <sup>c</sup>                                  | Q <sub>gd</sub>     |                                                                                                                        |                                                 | -    | 21     | -      |      |
| Gate Resistance                                                 | R <sub>g</sub>      | f = 1 MHz                                                                                                              |                                                 | 0.59 | 1.19   | 1.79   | Ω    |
| Turn-On Delay Time <sup>c</sup>                                 | t <sub>d(on)</sub>  | V <sub>DD</sub> = 15 V, R <sub>L</sub> = 0.3 Ω<br>I <sub>D</sub> ≅ 50 A, V <sub>GEN</sub> = 10 V, R <sub>g</sub> = 1 Ω |                                                 | -    | 18     | 27     | ns   |
| Rise Time <sup>c</sup>                                          | t <sub>r</sub>      |                                                                                                                        |                                                 | -    | 11     | 17     |      |
| Turn-Off Delay Time <sup>c</sup>                                | t <sub>d(off)</sub> |                                                                                                                        |                                                 | -    | 64     | 96     |      |
| Fall Time <sup>c</sup>                                          | t <sub>f</sub>      |                                                                                                                        |                                                 | -    | 11     | 17     |      |
| Source-Drain Diode Ratings and Characteristics <sup>b</sup>     |                     |                                                                                                                        |                                                 |      |        |        |      |
| Pulsed Current <sup>a</sup>                                     | I <sub>SM</sub>     |                                                                                                                        |                                                 | -    | -      | 480    | A    |
| Forward Voltage                                                 | V <sub>SD</sub>     | I <sub>F</sub> = 60 A, V <sub>GS</sub> = 0 V                                                                           |                                                 | -    | 0.81   | 1.5    | V    |

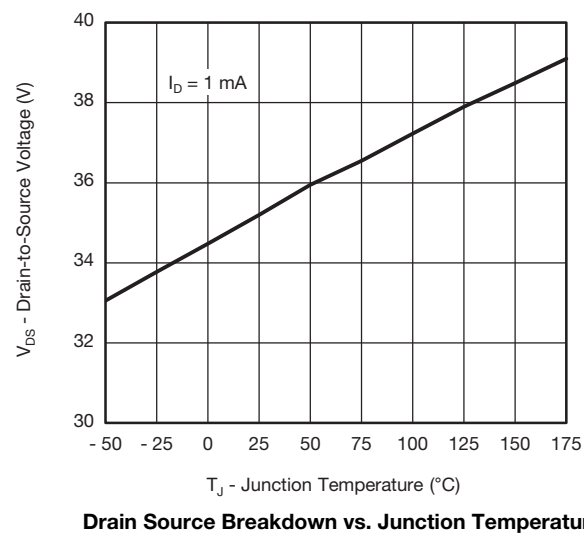
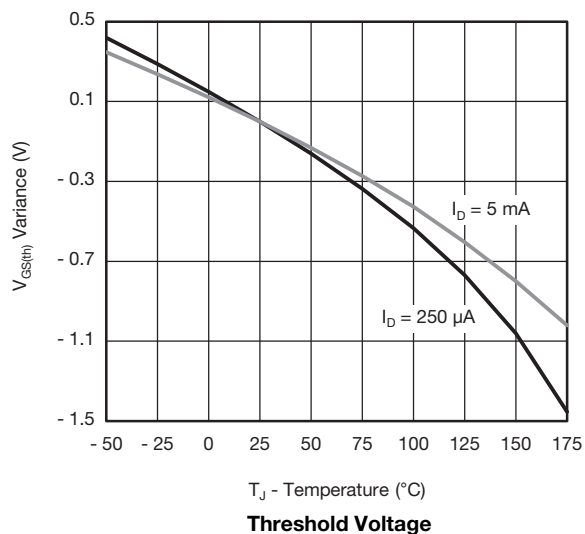
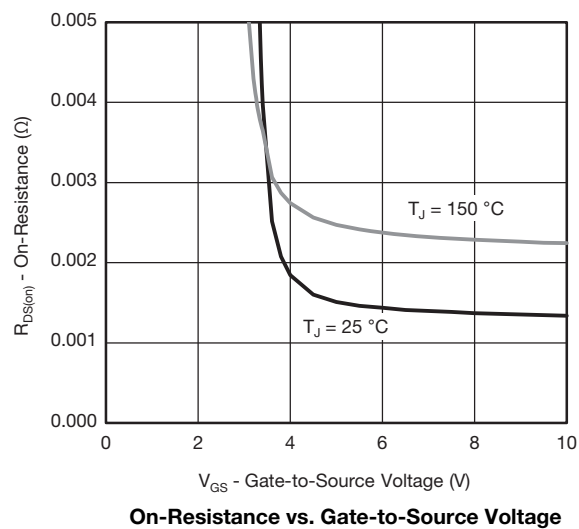
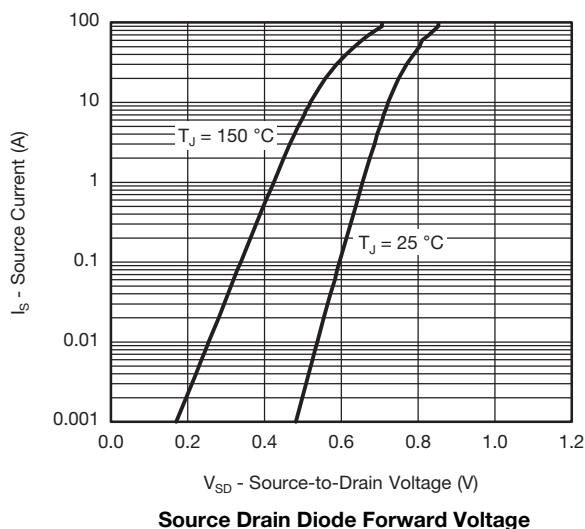
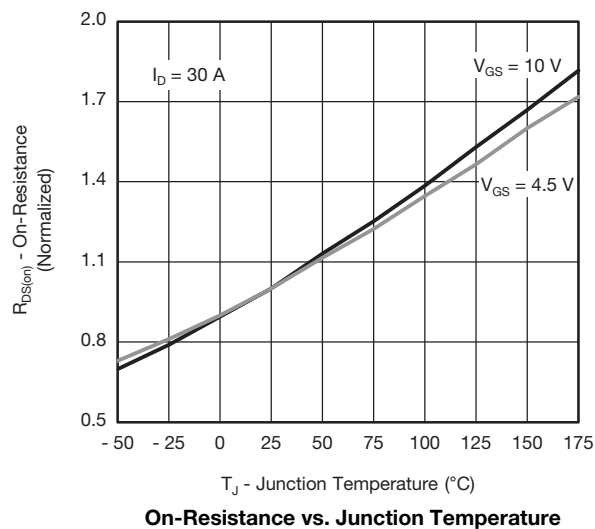
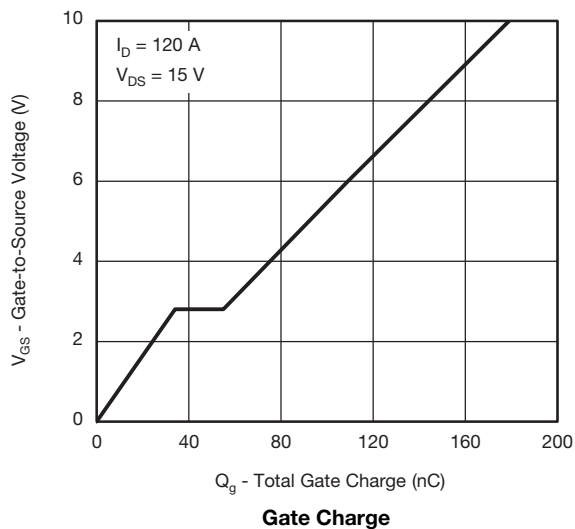
**Notes**

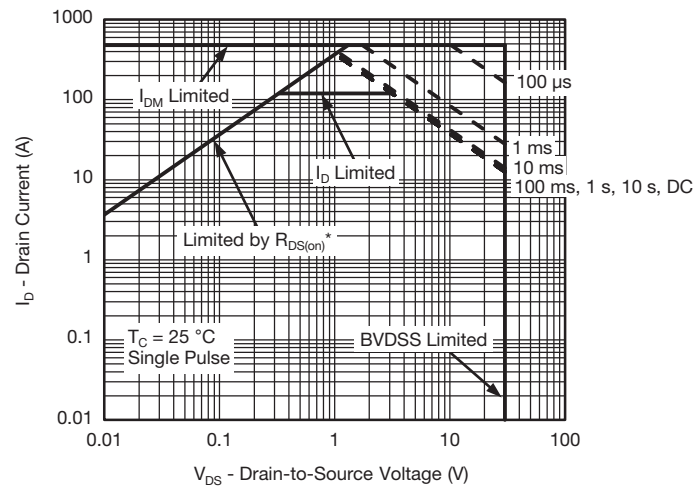
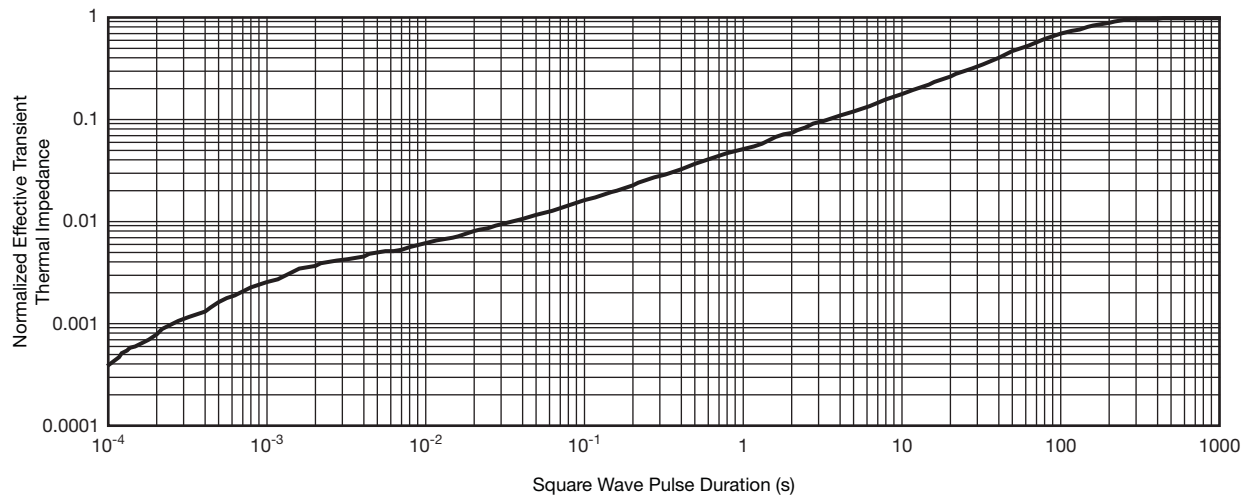
- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .  
b. Guaranteed by design, not subject to production testing.  
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

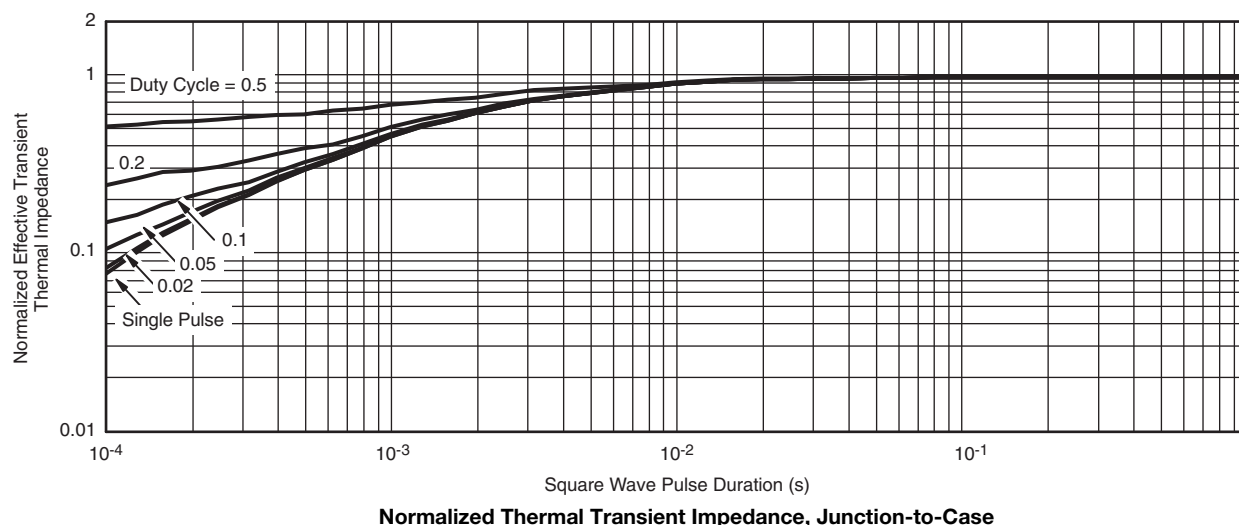
**TYPICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)


## TYPICAL CHARACTERISTICS ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)



**THERMAL RATINGS** ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)

**Safe Operating Area**

**Normalized Thermal Transient Impedance, Junction-to-Ambient**

## THERMAL RATINGS ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)



### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient ( $25\text{ }^{\circ}\text{C}$ )
  - Normalized Transient Thermal Impedance Junction-to-Case ( $25\text{ }^{\circ}\text{C}$ )
 are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?67333](http://www.vishay.com/ppg?67333).

**D<sup>2</sup>PAK / TO-263 and TO-262**

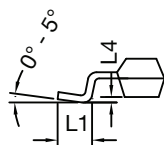
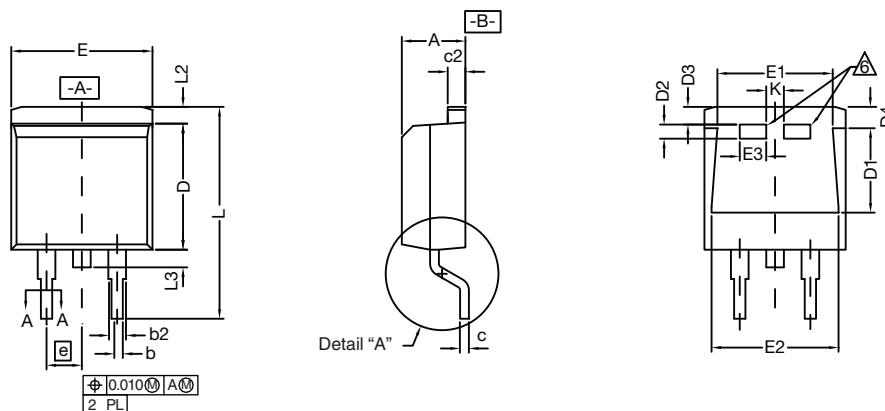
Ordering codes for the SQ rugged series power MOSFETs in the D<sup>2</sup>PAK / TO-263 and TO-262 packages:

| DATASHEET PART NUMBER | OLD ORDERING CODE <sup>a</sup> | NEW ORDERING CODE  |
|-----------------------|--------------------------------|--------------------|
| SQM100N04-2m7         | SQM100N04-2M7-GE3              | SQM100N04-2M7_GE3  |
| SQM100N10-10          | SQM100N10-10-GE3               | SQM100N10-10_GE3   |
| SQM110N05-06L         | SQM110N05-06L-GE3              | SQM110N05-06L_GE3  |
| SQM110P06-8m9L        | SQM110P06-8M9L-GE3             | SQM110P06-8M9L_GE3 |
| SQM120N02-1m3L        | SQM120N02-1M3L-GE3             | SQM120N02-1M3L_GE3 |
| SQM120N03-1m5L        | SQM120N03-1M5L-GE3             | SQM120N03-1M5L_GE3 |
| SQM120N04-1m7         | SQM120N04-1M7-GE3              | SQM120N04-1M7_GE3  |
| SQM120N04-1m7L        | SQM120N04-1M7L-GE3             | SQM120N04-1M7L_GE3 |
| SQM120N04-1m9         | SQM120N04-1M9-GE3              | SQM120N04-1M9_GE3  |
| SQM120N06-06          | SQM120N06-06-GE3               | SQM120N06-06_GE3   |
| SQM120N06-3m5L        | SQM120N06-3M5L-GE3             | SQM120N06-3M5L_GE3 |
| SQM120N10-09          | SQM120N10-09-GE3               | SQM120N10-09_GE3   |
| SQM120N10-3m8         | SQM120N10-3M8-GE3              | SQM120N10-3M8_GE3  |
| SQM120P04-04L         | SQM120P04-04L-GE3              | SQM120P04-04L_GE3  |
| SQM120P06-07L         | SQM120P06-07L-GE3              | SQM120P06-07L_GE3  |
| SQM200N04-1m1L        | SQM200N04-1M1L-GE3             | SQM200N04-1M1L_GE3 |
| SQM200N04-1m7L        | SQM200N04-1M7L-GE3             | SQM200N04-1M7L_GE3 |
| SQM200N04-1m8         | SQM200N04-1M8-GE3              | SQM200N04-1M8_GE3  |
| SQM25N15-52           | SQM25N15-52-GE3                | SQM25N15-52_GE3    |
| SQM35N30-97           | SQM35N30-97-GE3                | SQM35N30-97_GE3    |
| SQM40N10-30           | SQM40N10-30-GE3                | SQM40N10-30_GE3    |
| SQM40N15-38           | SQM40N15-38-GE3                | SQM40N15-38_GE3    |
| SQM40P10-40L          | SQM40P10-40L-GE3               | SQM40P10-40L_GE3   |
| SQM47N10-24L          | SQM47N10-24L-GE3               | SQM47N10-24L_GE3   |
| SQM50020EL            | -                              | SQM50020EL_GE3     |
| SQM50N04-4m0L         | SQM50N04-4M0L-GE3              | SQM50N04-4M0L_GE3  |
| SQM50N04-4m1          | SQM50N04-4M1-GE3               | SQM50N04-4M1_GE3   |
| SQM50P03-07           | SQM50P03-07-GE3                | SQM50P03-07_GE3    |
| SQM50P04-09L          | SQM50P04-09L-GE3               | SQM50P04-09L_GE3   |
| SQM50P06-15L          | SQM50P06-15L-GE3               | SQM50P06-15L_GE3   |
| SQM50P08-25L          | SQM50P08-25L-GE3               | SQM50P08-25L_GE3   |
| SQM60N06-15           | SQM60N06-15-GE3                | SQM60N06-15_GE3    |
| SQM60N20-35           | SQM60N20-35-GE3                | SQM60N20-35_GE3    |
| SQM85N15-19           | SQM85N15-19-GE3                | SQM85N15-19_GE3    |
| SQV120N10-3m8         | SQV120N10-3m8-GE3              | SQV120N10-3m8_GE3  |
| SQV120N06-4m7L        | -                              | SQV120N06-4m7L_GE3 |

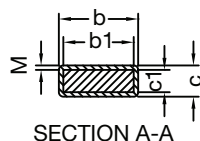
**Note**

a. Old ordering code is obsolete and no longer valid for new orders

## TO-263 (D<sup>2</sup>PAK): 3-LEAD



DETAIL A (ROTATED 90°)



SECTION A-A

### Notes

- Plane B includes maximum features of heat sink tab and plastic.
- No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- Pin-to-pin coplanarity max. 4 mils.
- \*: Thin lead is for SUB, SYB.  
Thick lead is for SUM, SYM, SQM.
- Use inches as the primary measurement.
-  This feature is for thick lead.

| DIM.                                                                                |            | INCHES    |       | MILLIMETERS |        |
|-------------------------------------------------------------------------------------|------------|-----------|-------|-------------|--------|
|                                                                                     |            | MIN.      | MAX.  | MIN.        | MAX.   |
| A                                                                                   |            | 0.160     | 0.190 | 4.064       | 4.826  |
| b                                                                                   |            | 0.020     | 0.039 | 0.508       | 0.990  |
| b1                                                                                  |            | 0.020     | 0.035 | 0.508       | 0.889  |
| b2                                                                                  |            | 0.045     | 0.055 | 1.143       | 1.397  |
| c*                                                                                  | Thin lead  | 0.013     | 0.018 | 0.330       | 0.457  |
|                                                                                     | Thick lead | 0.023     | 0.028 | 0.584       | 0.711  |
| c1                                                                                  | Thin lead  | 0.013     | 0.017 | 0.330       | 0.431  |
|                                                                                     | Thick lead | 0.023     | 0.027 | 0.584       | 0.685  |
| c2                                                                                  |            | 0.045     | 0.055 | 1.143       | 1.397  |
| D                                                                                   |            | 0.340     | 0.380 | 8.636       | 9.652  |
| D1                                                                                  |            | 0.220     | 0.240 | 5.588       | 6.096  |
| D2                                                                                  |            | 0.038     | 0.042 | 0.965       | 1.067  |
| D3                                                                                  |            | 0.045     | 0.055 | 1.143       | 1.397  |
| D4                                                                                  |            | 0.044     | 0.052 | 1.118       | 1.321  |
| E                                                                                   |            | 0.380     | 0.410 | 9.652       | 10.414 |
| E1                                                                                  |            | 0.245     | -     | 6.223       | -      |
| E2                                                                                  |            | 0.355     | 0.375 | 9.017       | 9.525  |
|  |            | 0.072     | 0.078 | 1.829       | 1.981  |
| e                                                                                   |            | 0.100 BSC |       | 2.54 BSC    |        |
| K                                                                                   |            | 0.045     | 0.055 | 1.143       | 1.397  |
| L                                                                                   |            | 0.575     | 0.625 | 14.605      | 15.875 |
| L1                                                                                  |            | 0.090     | 0.110 | 2.286       | 2.794  |
| L2                                                                                  |            | 0.040     | 0.055 | 1.016       | 1.397  |
| L3                                                                                  |            | 0.050     | 0.070 | 1.270       | 1.778  |
| L4                                                                                  |            | 0.010 BSC |       | 0.254 BSC   |        |
| M                                                                                   |            | -         | 0.002 | -           | 0.050  |
| ECN: T13-0707-Rev. K, 30-Sep-13                                                     |            |           |       |             |        |
| DWG: 5843                                                                           |            |           |       |             |        |

**RECOMMENDED MINIMUM PADS FOR D<sup>2</sup>PAK: 3-Lead**



Recommended Minimum Pads  
Dimensions in Inches/(mm)

[Return to Index](#)



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## Material Category Policy

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.**

**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**